



RTG4 Radiation Update Space Forum 2017

- J.J. Wang, Chief Engineer
- Nadia Rezzak, Staff Engineer
- Stephen Varela, Engineer

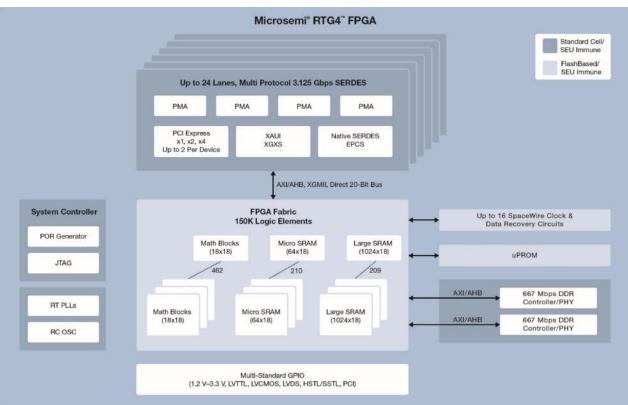
Agenda

- Introduction
- Chip Level TID and SEE Update
- Single Event Effects Update
 - Fabric Circuit Heavy-Ion Testing
 - PLL and SERDES Heavy-Ion Testing
 - Reprogramming in Space Flight
- Summary and Further Radiation Testing



RTG4 FPGAs





- Radiation tolerant Flash-based FPGA manufactured by UMC 65nm technology
- High-Speed Signal Processing
 - 300 MHz
 - 150K LE (STMRFF)
 - 5 Mbit SRAM (EDAC)
 - 462 Multipliers (DSP)
 - RT-PI I

- 24 x 3.125 Gbps SERDES
- Hardened for both TID and SEE
 - TID > 100 Krad
 - SFI immune
 - SEU/SET/SEFI

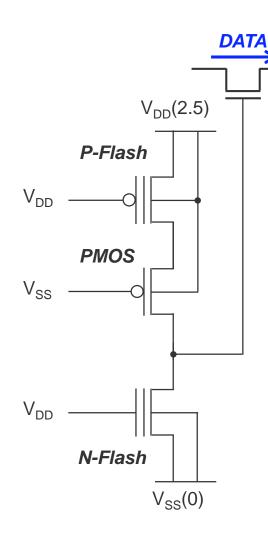


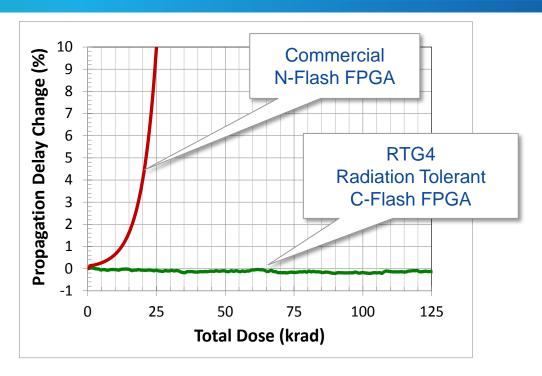
Flash-Cell Radiation Hardening



TID and SEE Hardened C-Flash Cell

Switch





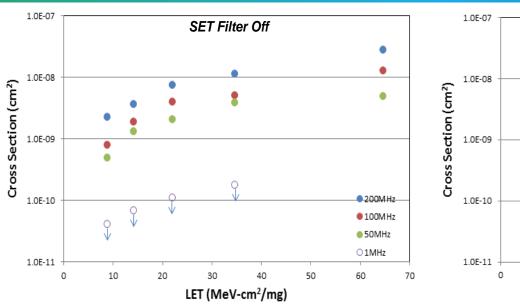
- NOR Flash architecture
- Charge storage for N-Flash or P-Flash is >10X of N-Flash memory; small V_T change (△V_T) by HI
- Switch has no degradation until Flash changes state and can tolerant V_T shift but still maintain performance: TID > 125krad
- Reprogramming succeeds after irradiated high LET-ion with high fluence (can reprogram every irradiated part)

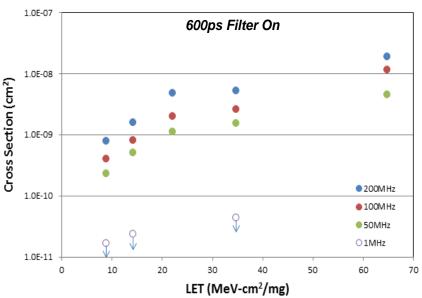


Fabric Circuits Radiation Update



Fabric FF (STMRFF) SET Filter Enable—2X Error Reduction





- No error observed at 1 MHz
- ⇒ Flip-flop TMR works to eliminate SEU at 1 MHz
- ⇒ Errors observed at 50 MHz, 100 MHz, and 200 MHz were all SET and not SEU
- Filter reduced SET by half

Device Family	Error Rate for GEO Min (Errors/bit-day)				
SmartFusion2 @ 1MHz	1.76 x 10 ⁻⁷				
RTG4 @ 1MHz	2.60 x 10 ⁻¹²				
RTG4 @ 200MHz	4.20 x 10 ⁻⁸				



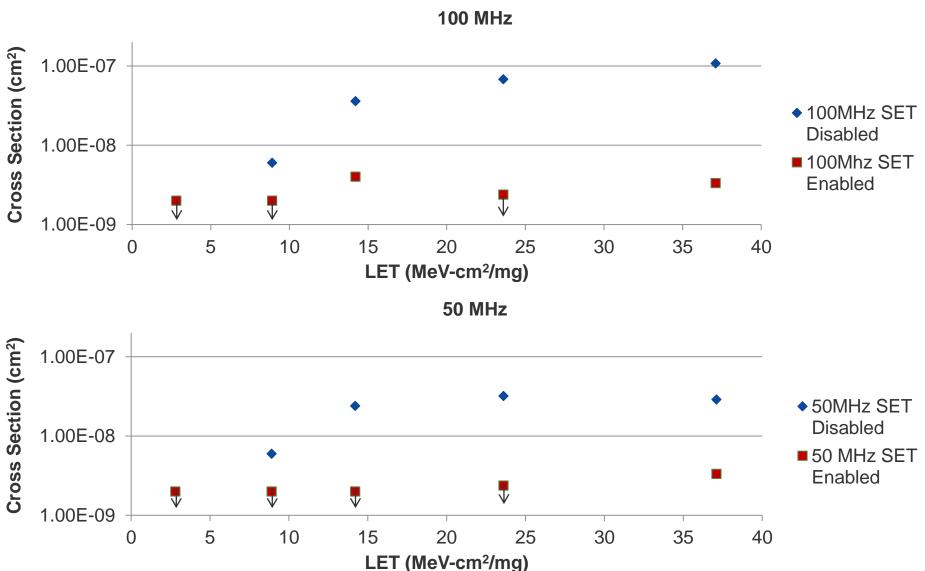
LBNL—RTG4 Mathblock SET Filter Testing

- Mathblock design with SET Filter enabled vs disabled are tested
 - Parallel Math Block Chains (25 stages)
 - Configured using cascade mode uses dedicated math block routing—Not going through the fabric
 - Frequencies: 50 MHz and 100 MHz
 - SET filter enabled (600 ps) vs disabled
- Hard Multiplier Accumulator macro (accumulation enabled) was tested with heavy ion and the sensitivity is confirmed for LET as low as 2.8 MeV.cm2/mg

- The (SET/SEU) errors accumulate and a reset is required
- Hard Multiplier AddSub macro (accumulation disabled)
 - Errors do not accumulate, SET errors are captured but no reset is necessary
 - SET Filter enabled vs. SET Filter disabled are tested
 - SET Filter is very efficient
 - The SET filter is able to mitigate most of the errors up to an LET of ~ 37 MeV.cm2/mg



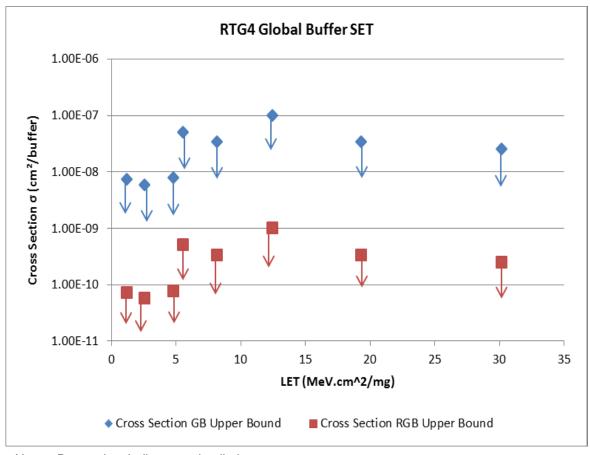
Math Blocks SET Filter Enable—10X Error Reduction





Global Clock Buffer

No SET observed in Global Buffer or Row Global Buffer for LET < 30 MeV-cm2/mg



Notes: Data points indicate testing limits.

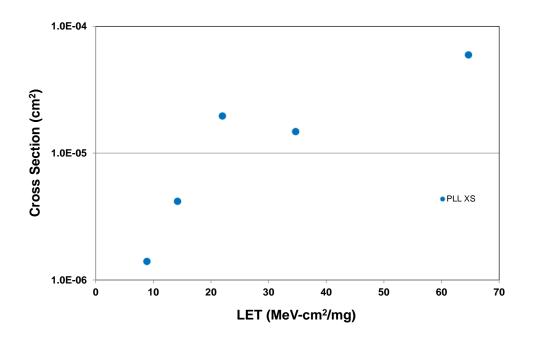


PLL and SERDES Radiation Update



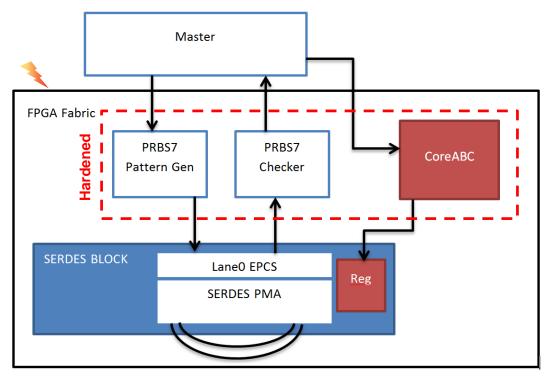
PLL

- PLL Single Event Functional Interrupt (SEFI) is defined by PLL loss of lock
- Heavy-Ion SEE Testing Results
 - PLL lost lock and self-recovers at LET < 65 MeV-cm2/mg
 - PLL lost lock and can be recovered by reset at LET = 65 MeV-cm2/mg
 - Lock loss < 100 us
- More testing is planned





SERDES SEE Test and SEFI Auto-Recover

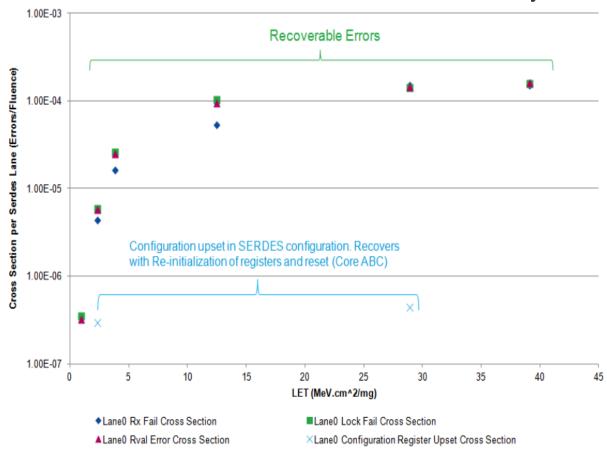


- 1. Controller in external master chip manages the testing system.
- 2. Configuration register in SERDES is SEE hardened but has upset.
- 3. When SERDES SEFI occurs, controller detects the event based on looped back data.
- 4. A command is sent to on-chip CoreABC, also built from SEE-hardened fabric logics, to refresh the configuration.



SERDES SEFI Results

- SERDES SEFI is defined by loss of link
 - Several signals were monitored
 - Loss of link is when returned data is invalid for 2+ consecutive cycles





SERDES Summary

- No DEVRST_N was required to recover link loss
- Most SEFI were self-recoverable
 - Others required reinitializing SERDES configuration registers using CoreABC

- Link loss was recoverable with duration in sub-millisecond range
- Plan for next testing:
 - Improve SERDES test design and measurement
 - Increase counter register size to prevent error saturation
 - Collect bit error rate with error correction for multiple transmissions



In-Flight Reprogramming—In-Beam Reprogramming Test



In-Beam RTG4 Reprogramming

- FlashPro used by customers
- Reprogramming in beam often gets interrupted
- No damage at LET ≤ 30.5
- Reprogram off-beam always successful after tried in beam, implying no destructive damage

Run	Effective LET	Effective Flux (lon/cm²/s)	Fluence until Prog Fail	Fluence (lon/cm²)	Reprogram Attempts	Reprogram Passed	Reprogram Functional	Off-Beam Reprogram Pass
23	1.2	1.00E+04	1.40E+06	1.40E+06	1	0	0	1
24	1.2	1.00E+04	3.40E+05	1.40E+06	1	0	0	1
25	1.2	1.00E+04	1.80E+05	6.00E+05		0	0	1
26	2.6	1.00E+04	4.30E+05	6.00E+05		0	0	1
27	8.2	1.00E+04	2.40E+05	1.41E+06	1	0	0	1
28	8.2	1.00E+04	2.55E+06	1.00E+07	8	0	0	1
29	11.6	1.00E+04	8.62E+05	1.00E+07	8	0	0	1
30	19.3	3.00E+03	4.86E+05	2.20E+06	3	0	0	1
31	19.3	3.00E+03	1.16E+06	2.20E+06	6	0	0	1
32	30.5	9.00E+02	2.99E+05	2.00E+06	12	0	0	1
33	30.5			2.00E+06		0	0	1
34	30.5	9.00E+02	3.36E+05	2.00E+06	13	0	0	1

This data implies that users can attempt re-programming multiple times until successful.

© 2017 Microsemi Corporation. Company Proprietary

• In space, the probability of a heavy-ion strike is low during short-cycle reprogramming



In-Beam Reprogramming Error

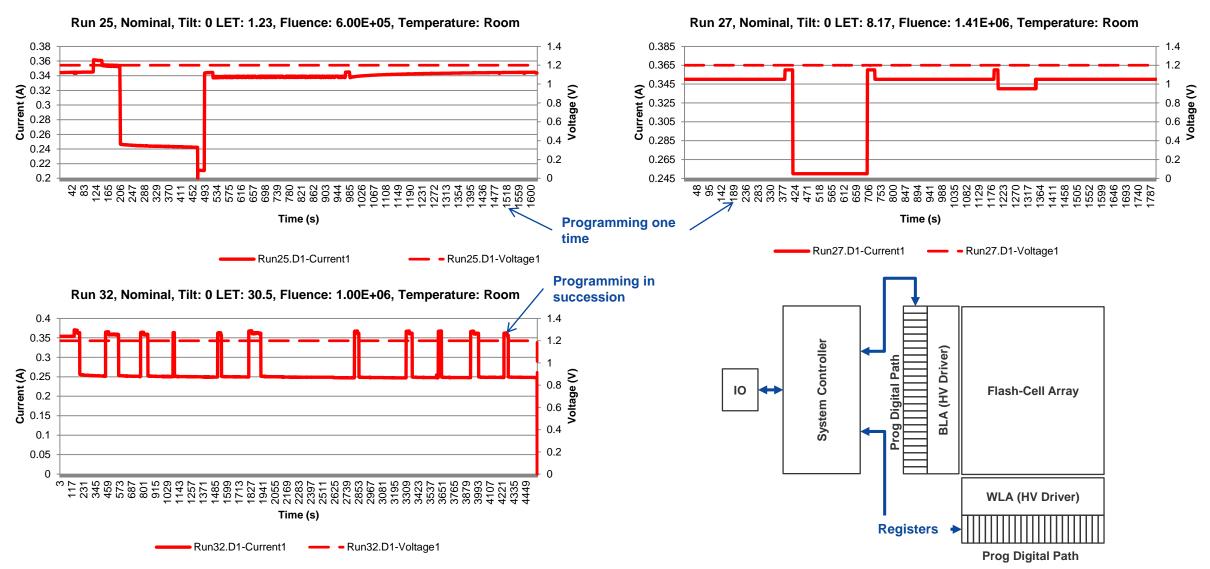
Example: Run 24, Bit stream error

```
programmer '87254' : Scan Chain...
programmer '87254' : Scan Chain PASSED
programmer '87254': Executing action PROGRAM
programmer '87254' : EXPORT ISC ENABLE RESULT[32] = 00004404
programmer '87254' : EXPORT CRCERR: [1] = 0
programmer '87254' : EXPORT ECCRCVR: [1] = 0
programmer '87254' : TEMPGRADE: ROOM
programmer '87254' : EXPORT TEMP: [8] = 44
programmer '87254' : Programming FPGA Array...
programmer '87254' : Bitstream Error.
programmer '87254' : blockNo: 12082
programmer '87254' : EXPORT DATA_STATUS_RESULT: [32] = 22a04024
programmer '87254' : EXPORT ERRORCODE: [5] = 04
programmer '87254' : EXPORT BSERRCODE: [8] = 40
programmer '87254' : EXPORT READ_DEBUG_INFO[128] = c444f07f000000000000000000010001
programmer '87254' : EXPORT DSN[128] = 00000000000000014b39070006001c
programmer '87254': Finished: Wed Jul 01 21:45:19 2015 (Elapsed time 00:02:17)
programmer '87254': Executing action PROGRAM PASSED.
```

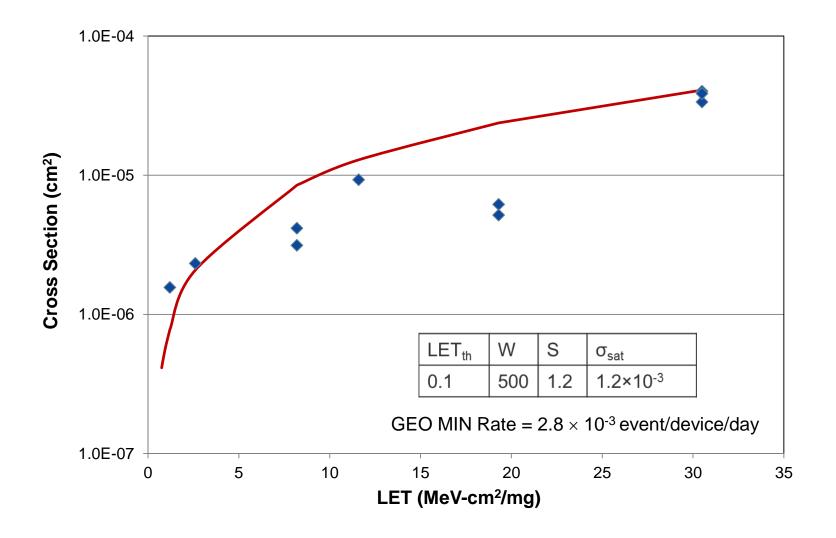
0-0-0-0-0



In-Beam Reprogramming SEFI—Register Upset



In-Beam Reprogramming Soft SEFI—Cross Section and Error Rate





In-Flight Reprogramming Guidance

- Preliminary guidance
 - Highly unlikely that a destructive event will occur during programming in space
 - Probability of success for programming in GEO is estimated ~ 99% or higher
 - It is highly likely that in space, no ion will disrupt programming
 - If an ion strike does disrupt programming, it is highly likely that the next programming attempt will succeed
 - Reprogramming after TID
 - Reprogramming can be accomplished at TID levels up to 50Krad
 - Sufficient for 10 years of GEO and > 20 years of LEO
- Further tests are planned
- Solutions for reprogramming in-flight
 - Use Microsemi DirectC programming algorithm on processor—Available Today
 - Use Microsemi RTG4 programming controller—Coming Soon
 - See video presentation Remote Programming of RTG4 FPGAs on orbit in today's Space Forum event



Prompt-Dose/Dose-Rate Testing

Contact Microsemi for more information

- Ken O'Neill Director of Marketing, Space, and Aviation 408-643-6179 ken.oneill@microsemi.com
- Minh Nguyen Senior Marketing Manager, Space 408-643-6283 minh.u.nguyen@microsemi.com



RTG4 Radiation Summary

Total Ionizing Dose	Stays within parametric limits > 125 Krad (Si)	
Single Event Latch-Up	No failure at facility limit of 103 MeV-cm ² /mg, 100°C	
Configuration Upset	No failure at facility limit of 103 MeV-cm ² /mg, 100°C	
Flip-Flop SEU	2.6E-12 errors/bit-day, GEO solar minimum, 1MHz	
LSRAM SEU	4.03E-8 errors/bit-day, GEO solar min (no EDAC)	1.1E-11 errors/bit-day, GEO solar min (with EDAC)
uSRAM SEU	3.33E-8 errors/bit-day, GEO solar min (no EDAC)	2.7E-13 errors/bit-day, GEO solar min (with EDAC)

- Test plan 2017 and Conference Papers and Publications
 - SET: Fabric, clocks, SpaceWire, MSIO, MSIOD
 - SEFI: PLL, SERDES, PCIe, DDR controllers, System Controller
 - Independent testing in progress (Aerospace Corp, NASA, JPL, ESA)
 - SEE Symposium and MAPLD Power Point presented in 5/2016 by Melanie Berg, NASA GSFC
 - 2016 HEART RTG4 Radiation Update
 - A Novel 65 nm Radiation Tolerant Flash Configuration Cell Used in RTG4 Field Programmable Gate Array
 - TID and SEE characterization of Microsemi's 4th generation radiation tolerant RTG4 flash-based FPGA
 - WP0191: Mitigation of Radiation Effects in RTG4 Radiation-Tolerant FPGAs
 - SEE Symposium /MAPLD May17 "SEE Induced VT Shift in Flash Cells of Flash-Based FPGAs"
 - NSREC July 17 "Investigation of TID and Dynamic Burn-In Induced VT Shift on RTG4 Flash-Based FPGA"



Thank You



Microsemi Corporate Headquarters

One Enterprise, Aliso Viejo, CA 92656 USA Within the USA: +1 (800) 713-4113 Outside the USA: +1 (949) 380-6100

Sales: +1 (949) 380-6136 Fax: +1 (949) 215-4996

email: sales.support@microsemi.com

www.microsemi.com

©2017 Microsemi Corporation. All rights reserved. Microsemi and the Microsemi logo are registered trademarks of Microsemi Corporation. All other trademarks and service marks are the property of their respective owners.

Microsemi Corporation (Nasdaq: MSCC) offers a comprehensive portfolio of semiconductor and system solutions for aerospace & defense, communications, data center and industrial markets. Products include high-performance and radiation-hardened analog mixed-signal integrated circuits, FPGAs, SoCs and ASICs; power management products; timing and synchronization devices and precise time solutions, setting the world's standard for time; voice processing devices; RF solutions; discrete components; enterprise storage and communication solutions, security technologies and scalable anti-tamper products; Ethernet solutions; Power-over-Ethernet ICs and midspans; as well as custom design capabilities and services. Microsemi is headquartered in Aliso Viejo, Calif., and has approximately 4,800 employees globally. Learn more at www.microsemi.com

Microsemi makes no warranty, representation, or guarantee regarding the information contained herein or the suitability of its products and services for any particular purpose, nor does Microsemi assume any liability whatsoever arising out of the application or use of any product or circuit. The products sold hereunder and any other products sold by Microsemi have been subject to limited testing and should not be used in conjunction with mission-critical equipment or applications. Any performance specifications are believed to be reliable but are not verified, and Buyer must conduct and complete all performance and other testing of the products, alone and together with, or installed in, any end-products. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the Buyer's responsibility to independently determine suitability of any products and to test and verify the same. The information provided by Microsemi hereunder is provided "as is, where is" and with all faults, and the entire risk associated with such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other IP rights, whether with regard to such information itself or anything described by such information. Information provided in this document is proprietary to Microsemi reserves the right to make any changes to the information in this document or to any products and services at any time without notice.